Roll No. ....

Total No. of Questions: 6]

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## EY-73

B.Tech. Ist Semester (CSE, IT & Elect.)
Examination, 2023-24

Basic Electronics Engineering
Paper - BE - 105

Time: 3 Hours

[Maximum Marks: 60

Note: -Ques. No. 1 is compulsory. Attempt any two parts from Ques. No. 2 to Ques. No. 6.

1. Write short answers:

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(1)

P.T.O.

- (i) Define Barrier Potential of a Diode.
- (ii) Give Features of Schottky Diode.
- (iii) What is Early effect?
- (iv) Give applications of 555 Timer.
- (v) How Lissajous figures are formed?
- 2. (a) What are Intrinsic and Extrinsic Semiconductors? Explain.
  - (b) Draw and Explain the V-I Characteristics of a PN junction diode.
  - (c) Explain the difference between Ideal and Practical Semiconductor diode.
- 3. (a) Explain the working of Varactor Diode.
  - (b) What is the function of a Rectifier circuit? Compare Half wave and Full wave rectifier circuit.
  - (c) Draw Clipper and Clamper circuits and explain working with the help of waveforms.
- 4. (a) Name different configurations of BJT and compare them.

- (b) Name different biasing circuits used in BJT and explain any one of them in detail.
- (c) Based on the construction, explain how FET's working is different from BJT.
- (a) Draw and explain the working of Comparator circuit using OPAMP.
  - (b) What are multivibrators? Give it's types.
  - (c) Give Ideal Characteristics of an OPAMP.
  - 6. (a) Draw the block diagram of CRO and explain how it's focusing system works.
    - (b) Where do we use storage oscilloscope? Give it's types.
    - (e) Write short note on Strain Gauge.